

Features

- Colorless transparency lens type
- $\phi 5\text{mm}$ (T-13/4) all plastic mold type
- Low power consumption
- High power, High speed type

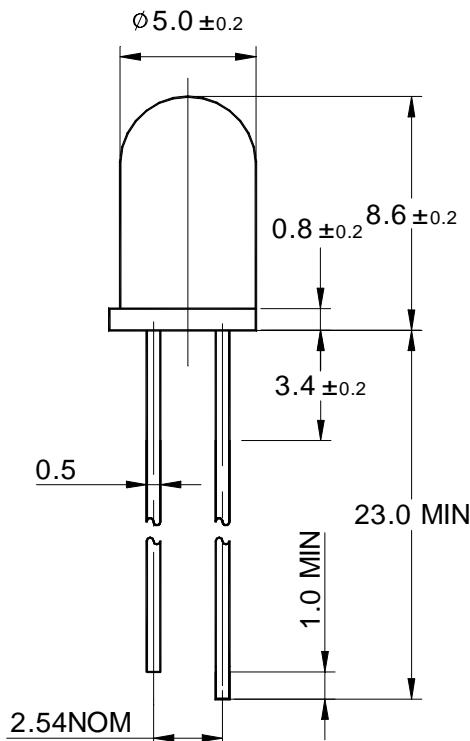
Applications

- Infrared remote control and free air transmission systems with low forward voltage and comfortable radiation angle requirements in combination with PIN photodiodes or phototransistors.

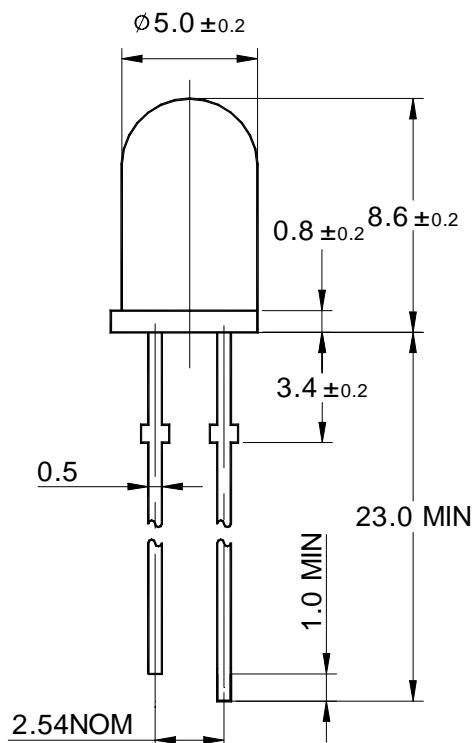
Outline Dimensions

unit : mm

STRAIGHT TYPE



STOPPER TYPE



PIN Connections
1. Cathode
2. Anode

SI5315-D(S)/SI5315-D(SB)

Absolute maximum ratings

Characteristic	Symbol	Ratings	Unit
Power Dissipation	P _D	150	mW
Forward Current	I _F	100	mA
* ¹ Peak Forward Current	I _{FP}	1	A
Reverse Voltage	V _R	4	V
Operating Temperature	T _{opr}	-25 85	
Storage Temperature	T _{stg}	-30 100	
* ² Soldering Temperature	T _{sol}	260 for 5 seconds	

*1.Duty ratio = 1/16, Pulse width = 0.1ms

*2.Keep the distance more than 2.0mm from PCB to the bottom of IRED package

Electrical Characteristics

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Forward Voltage	V _F	I _F = 50mA	-	1.5	2.0	V
Radiant Intensity	I _E	I _F = 50mA	30	70	-	mW/Sr
Peak Wavelength	λ _P	I _F = 50mA	-	875	-	nm
Spectrum Bandwidth		I _F = 50mA	-	45	-	nm
Rise Time	t _r	I _F = 50mA	-	15	-	ns
Reverse Current	I _R	V _R =4V	-	-	10	uA
* ³ Half angle	θ ^{1/2}	I _F = 50mA	-	±20	-	deg

*3. θ^{1/2} is the off-axis angle where the luminous intensity is 1/2 the peak intensity

Characteristic Diagrams

Fig. 1 I_F - V_F

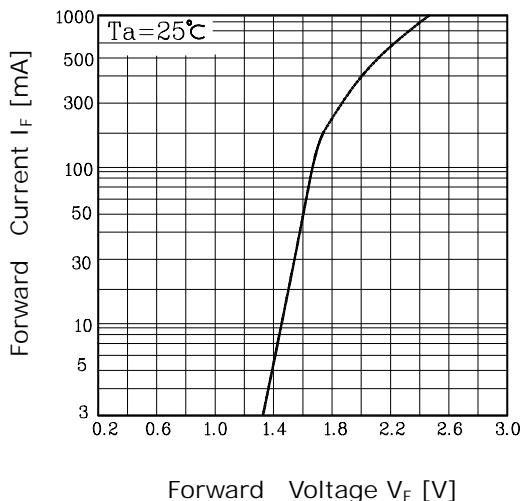


Fig. 2 I_V - I_F

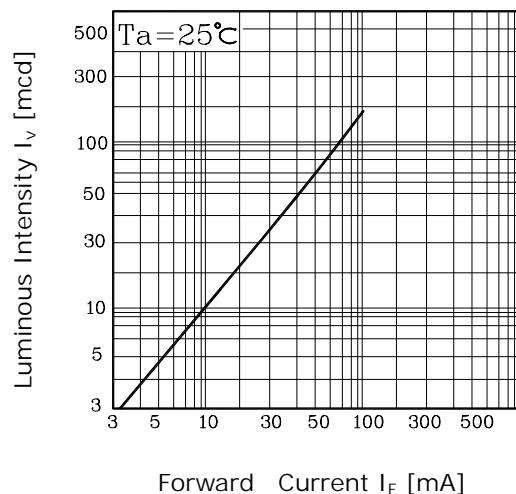


Fig. 3 I_F - T_a

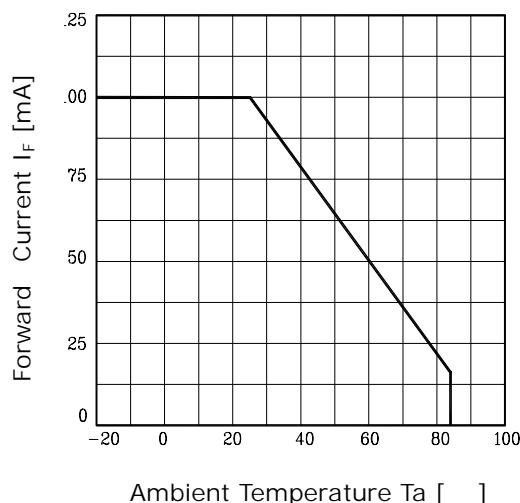


Fig. 4 Spectrum Distribution

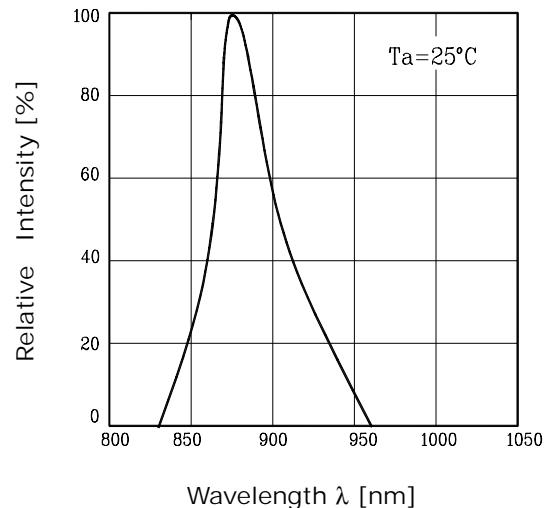


Fig. 5 Radiation Diagram

